EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	8	(recrystallized near polysilicon) with (gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 08:57
L2	2	(recrystallized near polysilicon) with (gate adj electrode) same capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 08:57
L3	2	(recrystallized near polysilicon) same (gate adj electrode) same capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 08:57
L4	4	(recrystallized near polysilicon) same (gate) same capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 08:58
L5	61	(recrystallized near polysilicon) and (gate) and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 08:58
L6	7	(recrystallized near polysilicon). clm. and (gate) and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 08:59
L7	5	(recrystallized near polysilicon). clm. and (gate).clm. and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:09
L8	2	(recrystallized near polysilicon). clm. and (gate).clm. and capacitor.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 08:58
L9	23	(recrystallized near polysilicon) near10 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:01

EAST Search History

L10	6	(recrystallized near polysilicon) near10 gate and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:02
L11	6	((recrystallized near polysilicon) near10 gate) and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:03
L12	62	((recrystallized near polysilicon)) and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:03
L13	28	((recrystallized near polysilicon near layer)) and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:06
L14	15	((recrystallized near polysilicon)) and capacitor.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:06
L15	2	((recrystallized near polysilicon)).clm. and capacitor.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:06
L16	62	((recrystallized near polysilicon)) and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/26 09:06